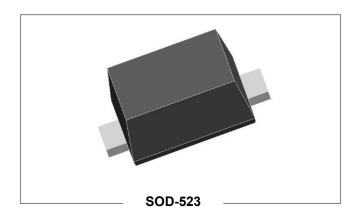






## **1N4148WT FAST SWITCHING DIODE**



#### **Features**

- Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- "-A" is an AEC-Q101 qualified device

## **Circuit Diagram**



### Maximum Ratings@TA=25°C unless otherwise specified

Parameter	Symbol	Value	Unit
Non-repetitive Peak Reverse Voltage	V <sub>RM</sub>	100	V
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	75	V
Working Peak Reverse Voltage	V <sub>RWM</sub>	75	
RMS Reverse Voltage	V <sub>R(RMS)</sub>	53	V
Average Rectified Output Current	Io	0.15	А
Non-repetitive Peak Forward Surge Current @ t=8.3ms	I <sub>FSM</sub>	300	mA
Power Dissipation	P <sub>D</sub>	150	mW
Thermal Resistance from Junction to Ambient	Roja	833	°C/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55~+150	°C

## Electrical Characteristics@TA=25°C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Reverse voltage	V <sub>(BR)</sub>	I <sub>R</sub> =1µA	75	-	-	V
Reverse current	IR	V <sub>R</sub> =75V	-	-	1	μA
		V <sub>R</sub> =20V	-	-	25	nA
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =1mA	-	-	0.715	
		I <sub>F</sub> =10mA	-	-	0.855	V
		I <sub>F</sub> =50mA	-	-	1	V
		I <sub>F</sub> =150mA	-	-	1.25	
Total capacitance	Ctot	V <sub>R</sub> =0V, f=1MHz	-	-	2	pF
Reverse recovery time	Trr	$I_F = I_R = 10$ mA, $Irr = 0.1 \times IR$ , $R_L = 100\Omega$	-	-	4	ns

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

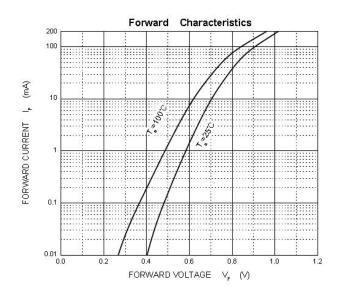
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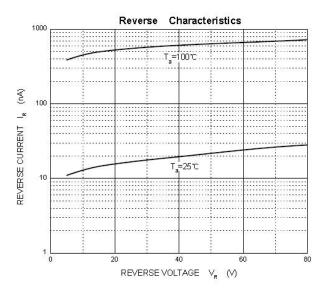


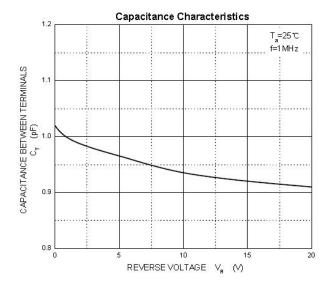


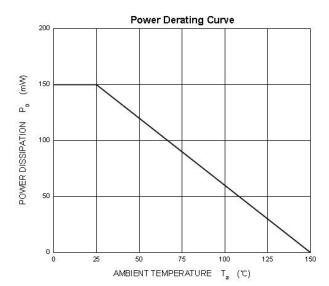


## **Ratings and Characteristics Curves**







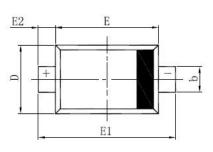


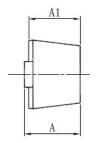






#### **Mechanical Dimensions SOD-523**





니	0
1	
	θ

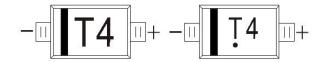
SYMBOL	Millimeters		Inches		
STINIBUL	Min.	Max.	Min.	Max.	
Α	0.510	0.770	0.020	0.031	
<b>A</b> 1	0.500	0.700	0.020	0.028	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	0.750	0.850	0.030	0.033	
E	1.100	1.300	0.043	0.051	
E1	1.500	1.700	0.059	0.067	
E2	0.200 REF		0.008 REF.		
L	0.010	0.070	0.001	0.003	
θ	7° REF		7° REF		

## **Ordering Information**

Device	Package	Shipping
1N4148WT	SOD-523	8000pcs / reel

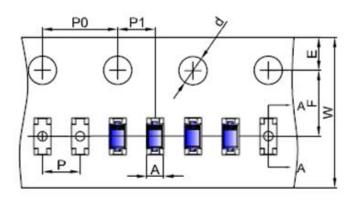
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

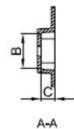
## **Marking Diagram**



Solid dot = Green molding compound device, if none, the normal device.

# **Carrier Tape & Reel Specification SOD-523**





CVMDOL	Millimeters			
SYMBOL	Min.	Max.		
Α	0.85	0.95		
В	1.89	1.99		
С	0.68	0.78		
d	1.40	1.60		
E	1.65	1.85		
F	3.40	3.60		
Р	1.90	2.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		

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